

MOSMIC[®] for TV-Tuner Prestage with 5 V Supply Voltage

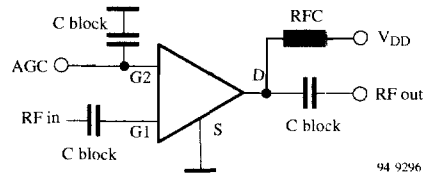
MOSMIC – MOS Monolithic Integrated Circuit

Electrostatic sensitive device.
Observe precautions for handling.



Applications

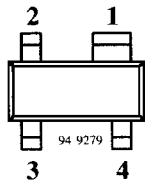
Low noise gain controlled input stages in UHF- and VHF-tuner with 5 V supply voltage.



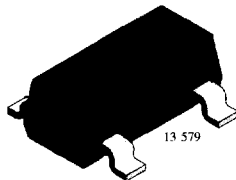
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Features

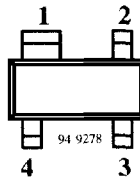
- Integrated gate protection diodes
- Low noise figure
- High gain
- Biasing network on chip
- Improved cross modulation at gain reduction
- High AGC-range
- SMD package



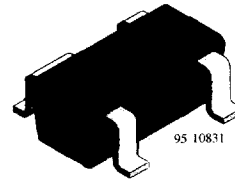
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S594T Marking: 594

Plastic case (SOT 143)

1 = Source; 2 = Drain; 3 = Gate 2; 4 = Gate 1

S594TR Marking: 94R

Plastic case (SOT 143R)

1 = Source; 2 = Drain; 3 = Gate 2; 4 = Gate 1

Absolute Maximum Ratings

| Parameters | Symbol | Value | Unit |
|---|-------------------|-------------|------------------|
| Drain source voltage | V_{DS} | 8 | V |
| Drain current | I_D | 20 | mA |
| Gate 1/gate 2-source peak current | $\pm I_{G1/G2SM}$ | 10 | mA |
| Gate 1/gate 2-source voltage | $\pm V_{G1/G2SM}$ | 6 | V |
| Total power dissipation $T_{amb} \leq 78^\circ\text{C}$ | P_{tot} | 160 | mW |
| Channel temperature | T_{Ch} | 150 | $^\circ\text{C}$ |
| Storage temperature range | T_{Stg} | -55 to +150 | $^\circ\text{C}$ |

Maximum Thermal Resistance

| Parameters | Symbol | Maximum | Unit |
|---|-------------|---------|------|
| Channel ambient on glass fibre printed board (25 x 20 x 1.5) mm ³ plated with 35 μm Cu | R_{thChA} | 450 | K/W |

Electrical DC Characteristics
 $T_{amb} = 25^{\circ}\text{C}$

| Parameters / Test Conditions | Symbol | Min. | Typ. | Max. | Unit |
|---|-----------------------|------|------|------|---------------|
| Gate 1-source breakdown voltage $\pm I_{G1S} = 10 \text{ mA}, V_{G2S} = V_{DS} = 0$ | $\pm V_{(BR)G1SS}$ | 7 | | 10 | V |
| Gate 2-source breakdown voltage $\pm I_{G2S} = 10 \text{ mA}, V_{G1S} = V_{DS} = 0$ | $\pm V_{(BR)G2SS}$ | 7 | | 10 | V |
| Gate 1-source leakage current $+V_{G1S} = 5 \text{ V}, V_{G2S} = V_{DS} = 0$ | $+I_{G1SS}$ | | | 50 | μA |
| Gate 1-source leakage current $-V_{G1S} = 5 \text{ V}, V_{G2S} = V_{DS} = 0$ | $-I_{G1SS}$ | | | 100 | μA |
| Gate 2-source leakage current $\pm V_{G2S} = 5 \text{ V}, V_{G1S} = V_{DS} = 0$ | $\pm I_{G2SS}$ | | | 20 | nA |
| Drain current $V_{DS} = 5 \text{ V}, V_{G1S} = 0, V_{G2S} = 4 \text{ V}$ | I_{DSS} | 50 | | 500 | μA |
| Self-biased operating current $V_{DS} = 5 \text{ V}, V_{G1S} = \text{nc}, V_{G2S} = 4 \text{ V}$ | I_{DSP} | 7 | 10 | 14 | mA |
| Gate 2-source cut-off voltage $V_{DS} = 5 \text{ V}, V_{G1S} = \text{nc}, I_D = 20 \mu\text{A}$ | $V_{G2S(\text{OFF})}$ | | 1.0 | | V |

Electrical AC Characteristics
 $V_{DS} = 5 \text{ V}, V_{G2S} = 4 \text{ V}, f = 1 \text{ MHz}, T_{amb} = 25^{\circ}\text{C}$

| Parameters / Test Conditions | Symbol | Min. | Typ. | Max. | Unit |
|--|----------------------|------|----------|------|----------|
| Forward transadmittance | $ y_{21s} $ | 20 | 24 | 28 | mS |
| Gate 1 input capacitance | C_{iss1} | | 2.1 | 2.5 | pF |
| Feedback capacitance | C_{rss} | | 20 | | fF |
| Output capacitance | C_{oss} | | 0.9 | | pF |
| Power gain $g_S = 2 \text{ mS}, g_L = 0.5 \text{ mS}, f = 200 \text{ MHz}$ $g_S = 3.3 \text{ mS}, g_L = 1 \text{ mS}, f = 800 \text{ MHz}$ | G_{ps} G_{ps} | 16.5 | 26 20 | | dB dB |
| AGC range $V_{DS} = 5 \text{ V}, V_{G2S} = 1 \text{ to } 4 \text{ V}, f = 800 \text{ MHz}$ | ΔG_{ps} | 40 | | | dB |
| Noise figure $g_S = 2 \text{ mS}, g_L = 0.5 \text{ mS}, f = 200 \text{ MHz}$ $g_S = 3.3 \text{ mS}, g_L = 1 \text{ mS}, f = 800 \text{ MHz}$ | F F | | 1 1.3 | | dB dB |

Caution for Gate 1 switch-off mode:

No external DC-voltage on Gate 1 in active mode!

Switch-off at Gate 1 with $V_{G1S} < 0.7 \text{ V}$ is feasible.

Using open collector switching transistor (inside of PLL), insert 10 k Ω collector resistor.

Common Source S-Parameters

$V_{DS} = 5\text{ V}$; $V_{GS} = 4\text{ V}$

| f/MHz | S_{11} | | S_{21} | | S_{12} | | S_{22} | |
|-------|----------|-------|----------|-------|----------|-------|----------|-------|
| | LOG MAG | ANG | LOG MAG | ANG | LOG MAG | ANG | LOG MAG | ANG |
| | dB | deg | dB | deg | dB | deg | dB | deg |
| 50 | -0.02 | -4.1 | 7.63 | 174.7 | -63.74 | 88.0 | -0.07 | -1.8 |
| 100 | -0.04 | -7.9 | 7.56 | 169.0 | -57.38 | 85.8 | -0.09 | -3.4 |
| 150 | -0.11 | -11.6 | 7.47 | 162.5 | -53.95 | 82.9 | -0.12 | -5.3 |
| 200 | -0.19 | -15.5 | 7.36 | 156.7 | -51.68 | 80.5 | -0.15 | -6.9 |
| 250 | -0.30 | -19.6 | 7.20 | 150.3 | -50.05 | 78.0 | -0.17 | -8.8 |
| 300 | -0.39 | -22.9 | 7.06 | 145.2 | -48.69 | 76.6 | -0.22 | -10.4 |
| 350 | -0.54 | -26.6 | 6.84 | 139.3 | -47.82 | 74.8 | -0.27 | -11.8 |
| 400 | -0.67 | -30.0 | 6.67 | 133.9 | -47.15 | 73.6 | -0.29 | -13.6 |
| 450 | -0.82 | -33.3 | 6.44 | 128.7 | -46.66 | 72.8 | -0.37 | -15.1 |
| 500 | -0.98 | -36.7 | 6.26 | 123.5 | -46.39 | 72.1 | -0.44 | -16.8 |
| 550 | -1.14 | -39.8 | 6.07 | 118.7 | -46.33 | 72.0 | -0.48 | -18.3 |
| 600 | -1.30 | -43.2 | 5.81 | 113.4 | -46.34 | 74.4 | -0.55 | -19.8 |
| 650 | -1.44 | -46.1 | 5.62 | 109.3 | -46.14 | 76.3 | -0.61 | -21.1 |
| 700 | -1.58 | -49.2 | 5.43 | 104.4 | -46.17 | 78.6 | -0.66 | -22.5 |
| 750 | -1.74 | -52.0 | 5.22 | 100.0 | -46.48 | 81.7 | -0.72 | -24.2 |
| 800 | -1.91 | -54.9 | 5.01 | 95.5 | -46.65 | 87.0 | -0.78 | -25.5 |
| 850 | -2.02 | -58.0 | 4.86 | 91.2 | -46.62 | 93.4 | -0.82 | -27.0 |
| 900 | -2.16 | -61.0 | 4.68 | 86.8 | -46.43 | 102.1 | -0.86 | -28.7 |
| 950 | -2.28 | -63.8 | 4.53 | 82.6 | -45.77 | 110.0 | -0.93 | -30.0 |
| 1000 | -2.43 | -66.6 | 4.29 | 78.4 | -45.10 | 114.9 | -1.01 | -31.4 |
| 1050 | -2.57 | -69.4 | 4.12 | 73.8 | -44.59 | 119.4 | -1.12 | -32.7 |
| 1100 | -2.74 | -72.4 | 3.93 | 69.9 | -44.05 | 126.3 | -1.18 | -34.2 |
| 1150 | -2.81 | -75.3 | 3.85 | 65.7 | -43.14 | 132.1 | -1.20 | -35.8 |
| 1200 | -2.93 | -78.0 | 3.74 | 62.0 | -42.24 | 138.1 | -1.23 | -37.3 |
| 1250 | -3.06 | -80.8 | 3.63 | 57.8 | -41.21 | 143.1 | -1.27 | -38.7 |
| 1300 | -3.16 | -83.8 | 3.47 | 53.4 | -40.03 | 146.5 | -1.39 | -40.1 |

Typical Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

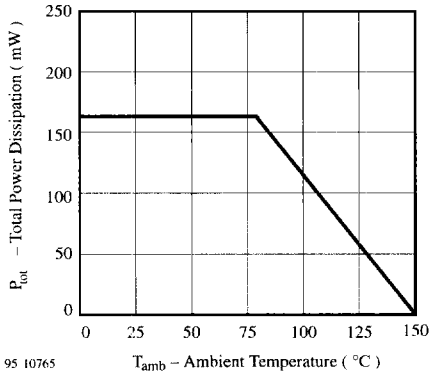


Figure 1. Total Power Dissipation vs. Ambient Temperature

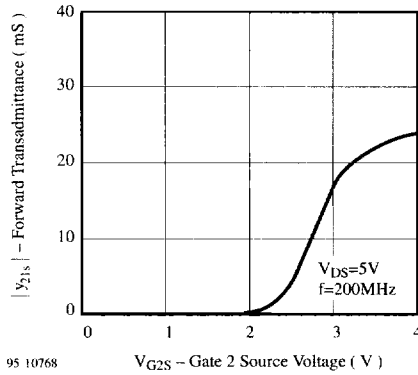


Figure 4. Forward Transadmittance vs. Gate 2 Source Voltage

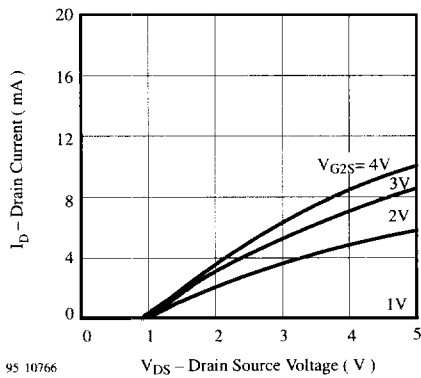


Figure 2. Drain Current vs. Drain Source Voltage

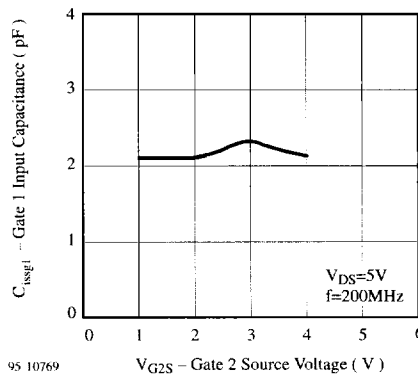


Figure 5. Gate 1 Input Capacitance vs. Gate 2 Source Voltage

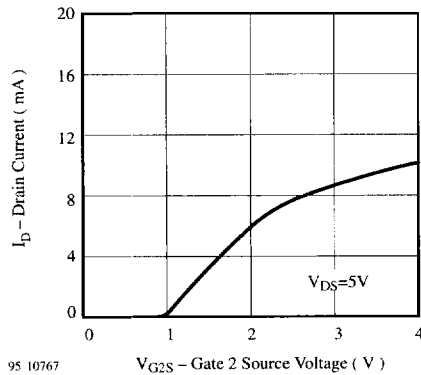


Figure 3. Drain Current vs. Gate 2 Source Voltage

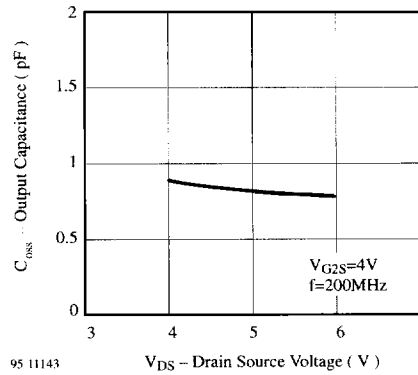


Figure 6. Output Capacitance vs. Drain Source Voltage

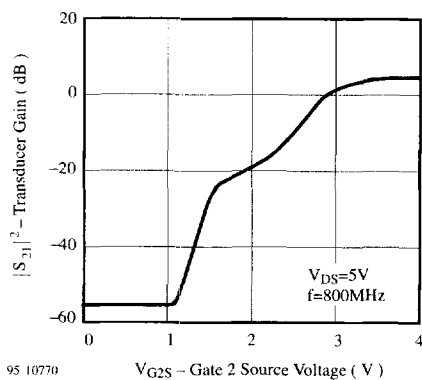


Figure 7. Transducer Gain vs. Gate 2 Source Voltage

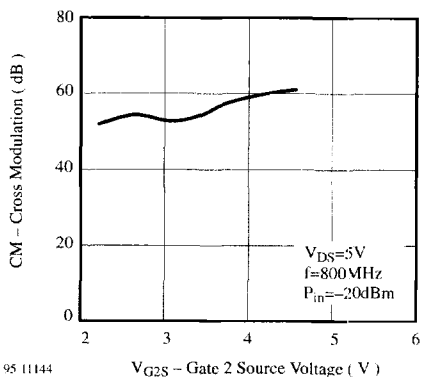


Figure 8. Gate 1 Cross Modulation vs. Gate 2 Source Voltage

$V_{DS} = 5 \text{ V}; V_{GS} = 4 \text{ V}; Z_0 = 50 \Omega$

S_{11}

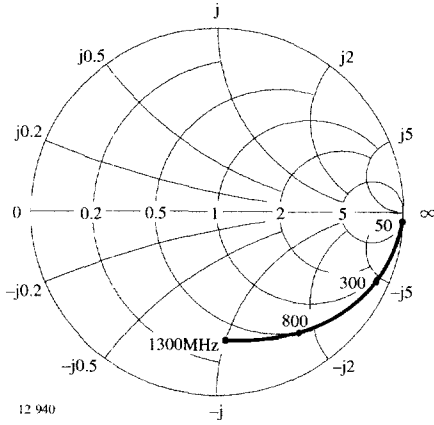
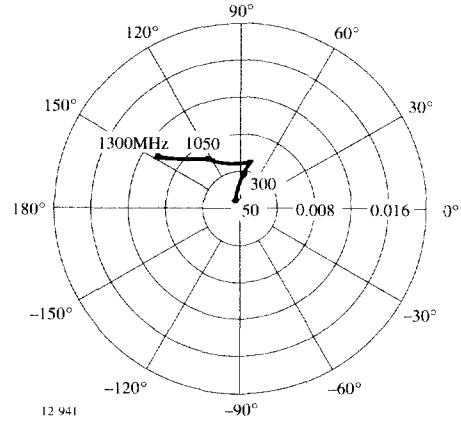
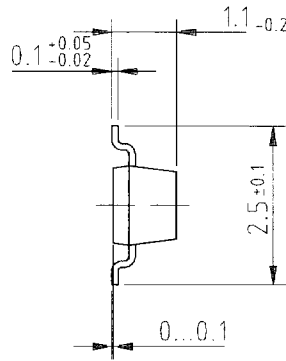
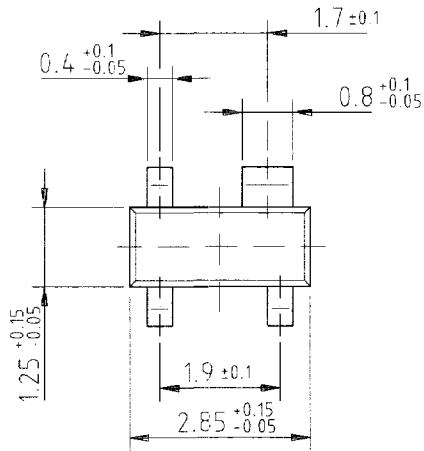


Figure 9. Input reflection coefficient

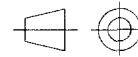
S_{12}



Dimensions of S594T in mm

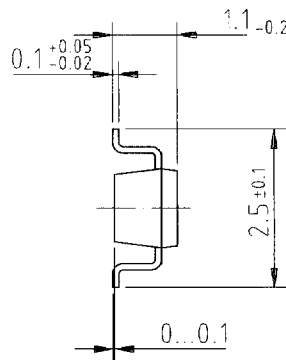
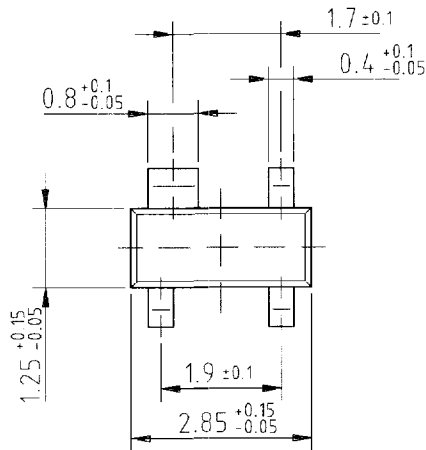


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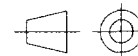


technical drawings
according to DIN
specifications

Dimensions of S594TR in mm



96 12239



technical drawings
according to DIN
specifications